#### 捷多邦,专业PCB打样工厂,24小时加急出货



#### N-Channel Silicon MOSFET

# 2SK2010 **Ultrahigh-Speed Switching Applications**

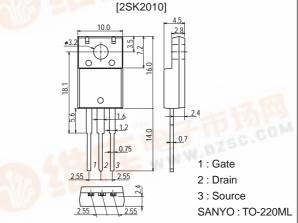
## **Features**

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Micaless package facilitating mounting.

## **Package Dimensions**

## unit:mm 2063A





## **Specifications**

## Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		250	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±30	V
Drain Current (DC)	ID		4	А
Drain Current (pulse)	IDP	PW≤10µs, duty cycle≤1%	16	A
Allowable Power Dissipation	PD	A State of the second	2.0	W
	۲D	Tc=25°C	25	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

# Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	250			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I <sub>G</sub> =±100µA, V <sub>DS</sub> =0	±30			V
Zero-Gate Votlage Drain Current	IDSS	V <sub>DS</sub> =250V, V <sub>GS</sub> =0		50	100	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±25V, V <sub>DS</sub> =0	13-		±10	μA
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.5	107	2.5	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =2A	2.5	4		S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =2A, V <sub>GS</sub> =10V		0.5	0.7	Ω

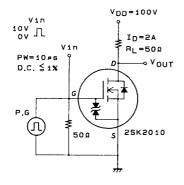
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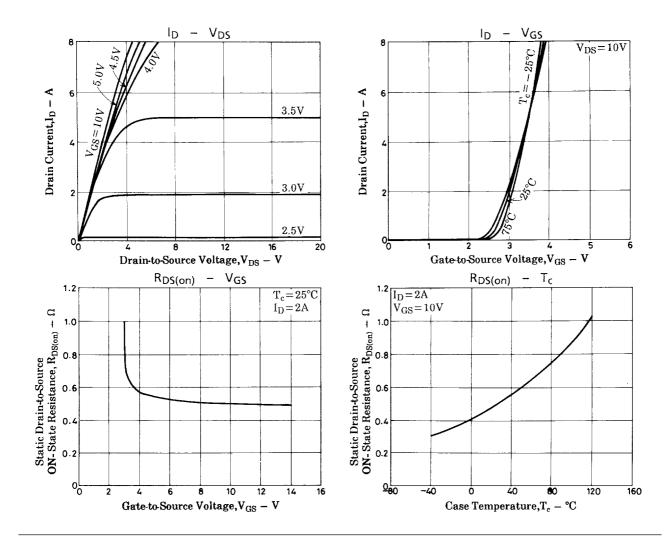
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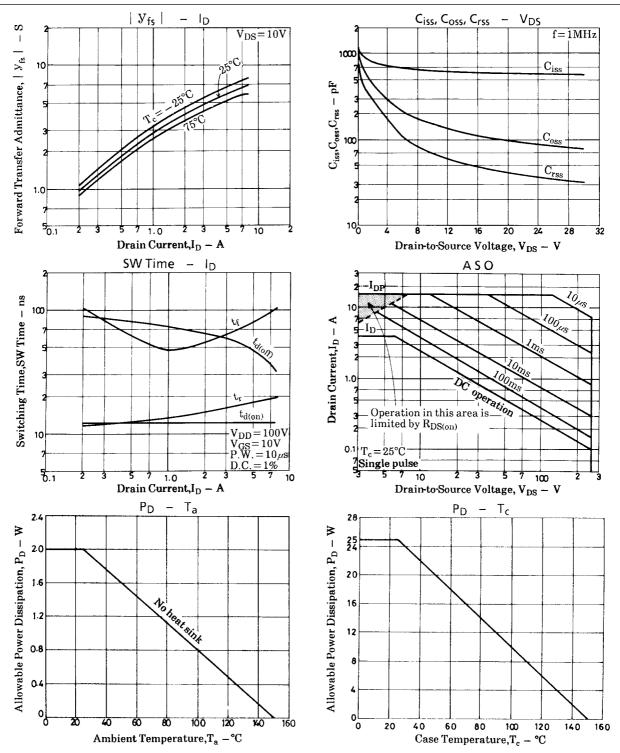
Parameter	Symbol	Conditions	Ratings		Unit
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz	6	00	pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz	1	00	pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		40	pF
Turn-ON Delay Time	<sup>t</sup> d(on)	See specified Test Circuit.		12	ns
Rise Time	tr	See specified Test Circuit.		15	ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		65	ns
Fall Time	t <sub>f</sub>	See specified Test Circuit.		55	ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =4A, V <sub>GS</sub> =0		.0 1.5	V

### **Switching Time Test Circuit**





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